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September 23, 2004

MS Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, Virginia 22313-1450

Re: U.S. Patent Application No.: 10/725,827
For: **ACTIVE MATRIX THIN FILM TRANSISTOR ARRAY BACKPLANE**
Inventors: Forbes, Charles, *et al.*
Filed: December 1, 2003
Our Ref. No.: VTW-010DVI

Dear Sir:

I enclose herewith for filing in the above-identified application the following:

1. Information Disclosure Statement;
2. PTO Form SB/08;
3. A Return Postcard.

No additional costs are believed to be due in connection with the filing of this Information Disclosure Statement. However, please charge any necessary fees in connection with the enclosed statement to our Deposit Order Account No. 12-0080. For this purpose, a duplicate of this sheet is attached.

I hereby certify that this correspondence is deposited with the United States Postal Service as first class mail in an envelope addressed to: MS Amendment, Commissioner for Patents, P.O. Box 1450, Alexandria, Virginia 22313-1450 on:

9/23/04
Date

Anthony A. Laurentano Registration No. 38,220

Respectfully submitted,
LAHIVE & COCKFIELD, LLP

Anthony A. Laurentano
Registration No. 38,220
Attorney for Applicants



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the application of: Forbes, Charles, *et al.*

Serial No.: 10/725,827

Filed: December 1, 2003

For: *ACTIVE MATRIX THIN FILM TRANSISTOR
ARRAY BACKPLANE*

Attorney Docket No.: VTW-010DV1

Group Art Unit: 2673

Examiner: NOT YET ASSIGNED

MS Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, Virginia 22313-1450

Certificate of First Class Mailing (37 CFR §1.8(a))

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9/23/04
Date of Signature and of Mail Deposit

By:

Anthony A. Laurentano
Reg. No.: 58,200
Attorney for Applicants

INFORMATION DISCLOSURE STATEMENT

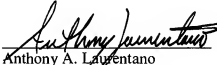
Dear Sir:

For the Examiner's convenience in reviewing this application, Applicants submit a consolidated PTO Form SB-08, listing all references cited during the prosecution of the parent applications. The present application is a continuation of U.S. Serial No. 10/300514, filed November 20, 2002 (Atty. Docket No. VTW-010). All references listed on the enclosed PTO Form SB-08 have been previously cited by or submitted to the Office in the prior application, and, in accordance with 37 CFR §1.98(d), copies of the of the references are not enclosed but will be provided upon request.

This statement is not to be interpreted as a representation that the cited publications are material, that an exhaustive search has been conducted, or that no other relevant information exists. Nor shall the citation of any publication herein be construed *per se* as a representation that such publication is prior art. Moreover, Applicants understand that the Examiner will make an independent evaluation of the cited publications.

Under 37 CFR § 1.97(b)(3), no additional costs are believed to be due in connection with the filing of this disclosure. If, however, a first Office Action on the merits issues in this application bearing a mailing date prior to the date of this Information Disclosure Statement, please charge any appropriate fee as required under 37 CFR § 1.17(p) to our Deposit Order Account No. 12-0080.

Respectfully submitted,
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Substitute for form 1449A/B/PTO				Complete if Known	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary)				Application Number	10725,827
				Filing Date	December 1, 2003
				First Named Inventor	Forbes, Charles
				Art Unit	2673
				Examiner Name	Not Yet Assigned /Prabodh Dharia/
Sheet	1	of	4	Attorney Docket Number	VTW-010DV1

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code ² (if known)			
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		Country Code ³ -Number ⁴ -Kind Code ⁵ (if known)			
/P	A26	WO 98/03896 A1	01-29-1998	JACOBSON, J.M.	

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NON PATENT LITERATURE DOCUMENTS					
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.			
/P	A27	BAEUERLE, P.A., et al. "4.3: A MIM-driven transmissive display with color filters on 2-in.-diagonal plastic substrates." SID 99 Digest, pp. 414-17.			

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Examiner Signature	/Prabodh Dharia/	Date Considered	03/06/2008
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Substitute for form 1449A/B/PTO <h2 style="text-align: center;">INFORMATION DISCLOSURE STATEMENT BY APPLICANT</h2> <p style="text-align: center;">(Use as many sheets as necessary)</p>				Complete if Known Application Number 10/725,827 Filing Date December 1, 2003 First Named Inventor Forbes, Charles Art Unit 2673 Examiner Name Not Yet Assigned /Prabodh Dharial/ Attorney Docket Number VTW-010DV1	
Sheet	2	of	4		

FOREIGN PATENT DOCUMENTS							
Examiner Initials ¹	Cite No.	Foreign Patent Document		Publication Date	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	† ²
		Country Code ³ -Number ⁴ -Kind Code ⁵ (if known)		MM-DD-YYYY			
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Examiner Signature	/Prabodh Dharial/	Date Considered	03/10/2008
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Substitute for form 1449A/B/PTO <h2 style="text-align: center; margin: 0;">INFORMATION DISCLOSURE STATEMENT BY APPLICANT</h2> <p style="text-align: center; margin: 0;">(Use as many sheets as necessary)</p>				Complete if Known Application Number 10/725,827 Filing Date December 1, 2003 First Named Inventor Forbes, Charles Art Unit 2673 Examiner Name Not Yet Assigned /Prabodh Dharia/ Attorney Docket Number VTW-010DV1	
Sheet	3	of	4		

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Examiner Signature	/Prabodh Dharia/	Date Considered	03/10/2008
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				Application Number	10/725,827
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				First Named Inventor	Forbes, Charles
				Art Unit	2673
				Examiner Name	Not Yet Assigned /Prabodh Dharia/
				Attorney Docket Number	VTW-010DV1
Sheet	4	of	4		

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